

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	11502	257/68,71,295-314,324-326.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 15:46
L2	2421	438/3,240.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 15:46
L3	13417	1 or 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 15:46
L4	3	3 and (((digit write) near line\$1) (conductive near (layer film))) near2 (beneath below underneath) near2 (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 15:50
L5	4	3 and (((digit write) near line\$1) (conductive near (layer film))) near2 (beneath below underneath) near2 (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:07
L6	3	("20020036331"   "20040021190"   "6396735").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 15:54
L7	3	("6165803"   "6174737"   "6560135").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 15:58
L8	3	("6351408"   "6359805"   "6392924").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 16:00
L9	8	("5075247"   "5329486"   "5352622"   "5424236"   "5640343"   "5768181"   "5861328"   "6048739").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 16:02
L10	453232	"257"/\$.ccls. "438"/\$.ccls. "365"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:06

L11	1	10 and (((digit write) near line\$1) (conductive near (layer film))) near (beneath below underneath) near (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:44
L12	35	10 and (((digit write) near line\$1) (conductive near (layer film))) near5 (beneath below underneath) near5 (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:22
L13	5	("5940319"   "6055179"   "6104632"   "6111784"   "6226197").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 16:19
L14	95	10 and (((digit write) near line\$1) (conductive near (layer film))) with (beneath below under underneath) with (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:47
L15	3	("6587371"   "6649953"   "6657270").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 16:34
L16	4	("20030142540"   "5734605"   "6587371"   "6657270").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/14 16:40
L17	330	10 and (((first second) near (digit write) near line\$1) (conductive near (layer film))) with (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:47
L18	12	10 and (((first second) near (digit write) near line\$1)) with (beneath below under underneath) with (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:51
L19	27	10 and (((first near (digit write) near line\$1)) with ((second near (digit write) near line\$1)) with (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:55
L20	28	(((first near (digit write) near line\$1)) with ((second near (digit write) near line\$1)) with (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:57

L21	110	(((first near (digit write) near line\$1)) and ((second near (digit write) near line\$1)) and (MRAM MTJ (magnetic near resistor) magnetoresist\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/14 16:57
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